

## **DPDT SWITCH GaAs MMIC**

#### **■** GENERAL DESCRIPTION

The NJG1657MD7 is a GaAs DPDT switch featured low insertion loss, high isolation and small size package, and suited for mobile terminal applications.

The NJG1657MD7 switches a path between common RF port and five RF ports by three bit control signal from 1.7V of logical high voltage. In addition, this switch includes ESD protection circuits for good ESD tolerance.

The NJG1657MD7 is available in a very small, lead-free, halogen-free, 1.6mm x 1.6mm x 0.397 mm, 14-pin EQFN14-D7 package.

#### **■ PACKAGE OUTLINE**



NJG1657MD7

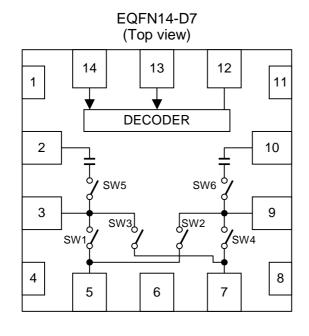
## **■ FEATURES**

Low insertion loss
 High isolation
 0.3dB typ. @f=0.9GHz, P<sub>IN</sub>=30dBm
 32dB typ. @f=0.9GHz, P<sub>IN</sub>=30dBm

◆ High power handling
P<sub>-0.1dB</sub>=33dBm min. @f=0.9GHz, V<sub>DD</sub>=2.85V

◆ Package EQFN14-D7 (Package size: 1.6x1.6x0.397mm typ.)

## **■ PIN CONFIGURATION**



## Pin connection

1. GND 8. GND
2. GND 9. P2
3. P1 10. GND
4. GND 11. GND
5. P3 12. VDD
6. GND 13. CTL1
7. P4 14. CTL2
\*Exposed PAD: GND

## **■ TRUTH TABLE**

"High"=V<sub>CTL(H)</sub>, "Low"=V<sub>CTL(L)</sub>

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PATH	CTL1	CTL2	SW1	SW2	SW3	SW4	SW5	SW6
P1-P3	Low	Low	ON	OFF	OFF	ON	OFF	ON
P1-P4	High	Low	OFF	ON	ON	OFF	OFF	ON
P2-P3	Low	High	OFF	ON	ON	OFF	ON	OFF
P2-P4	High	High	ON	OFF	OFF	ON	ON	OFF

NOTE: Please note that any information on this catalog will be subject to change.

## ■ ABSOLUTE MAXIMUM RATINGS

 $T_a=+25^{\circ}C, Z_s=Z_l=50 \text{ ohm}$ 

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PARAMETER	SYMBOL	CONDITIONS	CONDITIONS	UNITS
RF Input Power	P <sub>IN</sub>	V <sub>DD</sub> =2.85V, V <sub>CTL</sub> =0/2.6V	36	dBm
Supply Voltage	$V_{DD}$	VDD terminal	5.0	V
Control Voltage	V <sub>CTL</sub>	CTL1, CTL2 terminal	5.0	V
Power Dissipation	$P_D$	4-layer FR4 PCB with through-hole (74.2x74.2mm), T <sub>j</sub> =150°C	1300	mW
Operating Temp.	$T_{opr}$		-40~+95	°C
Storage Temp.	$T_{stg}$		-55~+150	°C

## ■ ELECTRICAL CHARACTERISTICS1 (DC CHARACTERISTICS)

General conditions: V<sub>DD</sub>=2.85V, V<sub>CTL(L)</sub>=0V, V<sub>CTL(H)</sub>=2.6V, T<sub>a</sub>=+25°C, Z<sub>S</sub>=Z<sub>I</sub>=50 ohm, with application circuit

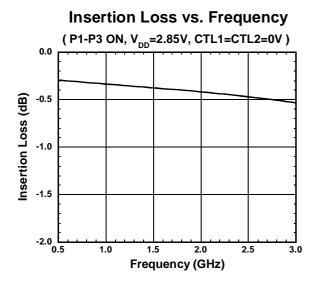
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage	$V_{DD}$		2.5	2.85	4.5	V
Operating Current	I <sub>DD</sub>	P <sub>IN</sub> =30dBm	-	50	100	μΑ
Control Voltage (LOW)	V <sub>CTL(L)</sub>		0	1	0.5	V
Control Voltage (HIGH)	V <sub>CTL(H)</sub>		1.7	2.6	4.5	V
Control Current	Ictl		-	5	10	μА

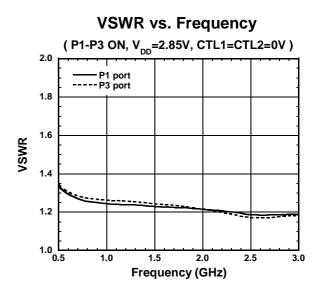
# ■ ELECTRICAL CHARACTERISTICS2 (RF CHARACTERISTICS) General conditions: V<sub>DD</sub>=2.85V, V<sub>CTI (I)</sub>=0V, V<sub>CTI (I)</sub>=2.6V, T<sub>a</sub>=+25°C, Z<sub>S</sub>=Z<sub>I</sub>=50 ohm, with application circuit

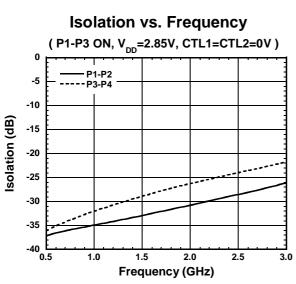
General conditions: $V_{DD}=2.85V$ , $V_{CTL(L)}=0V$ , $V_{CTL(H)}=2.6V$ , $T_a=+25^{\circ}C$ , $Z_S=Z_I=50$ ohm, with application circuit						
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Insertion Loss 1	LOSS1	f=0.9GHz, P <sub>IN</sub> =30dBm	-	0.30	0.45	dB
Insertion Loss 2	LOSS2	f=1.9GHz, P <sub>IN</sub> =30dBm	-	0.40	0.55	dB
Isolation 1	ISL1	f=0.9GHz, P <sub>IN</sub> =30dBm	30	32	-	dB
Isolation 2	ISL2	f=1.9GHz, P <sub>IN</sub> =30dBm	24	26	-	dB
0.1dB Compression input power	P <sub>-0.1dB</sub>	f=0.9GHz	33	35	-	dBm
2nd Harmonic Suppression	2fo	f=0.9GHz, P <sub>IN</sub> =30dBm	-	-75	-60	dBc
3rd Harmonic Suppression	3fo	f=0.9GHz, P <sub>IN</sub> =30dBm	-	-75	-60	dBc
VSWR (PC, P1, P2)	VSWR	f=0.9GHz, ON State	-	1.2	1.4	
Switching time	$T_{SW}$		-	2	5	μS

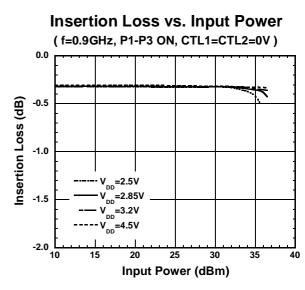
## **■ TERMINAL INFORMATION**

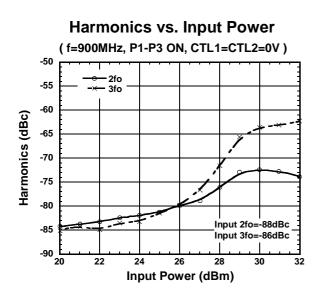
No.	SYMBOL	DESCRIPTION
1,2,4,6,8, 10,11	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
3	P1	RF input / output port. External capacitor is required to block the DC bias voltage of internal circuit.
5	P3	RF input / output port. External capacitor is required to block the DC bias voltage of internal circuit.
7	P4	RF input / output port. External capacitor is required to block the DC bias voltage of internal circuit.
9	P2	RF input / output port. External capacitor is required to block the DC bias voltage of internal circuit.
12	VDD	A supply voltage terminal (+2.5~+4.5V). Please place a bypass capacitor between this and GND for avoiding RF noise from outside.
13	CTL1	Control port "High love" is DC +4.7\/ 4.5\/ "Love love" is DC + 2.5\/
14	CTL2	Control port. "High level" is DC +1.7V~4.5V, "Low level" is DC 0~+0.5V.

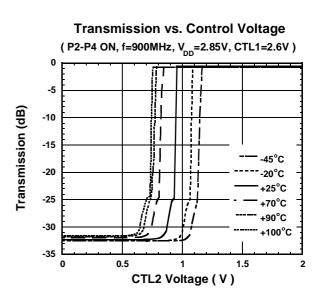


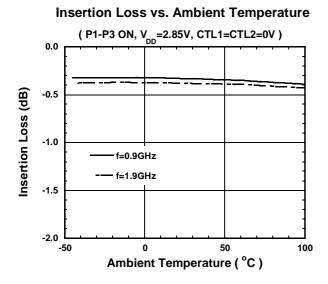


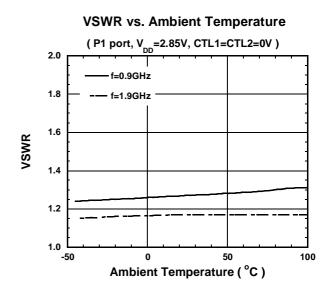


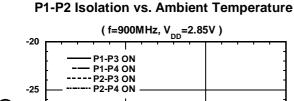


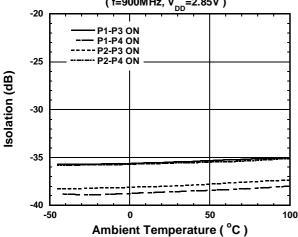




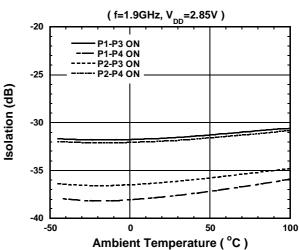




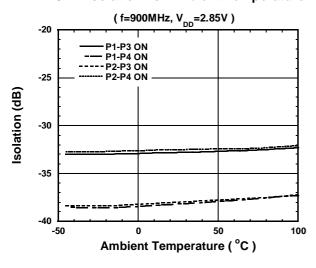




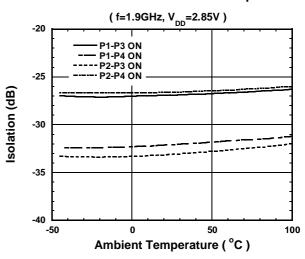
P1-P2 Isolation vs. Ambient Temperature

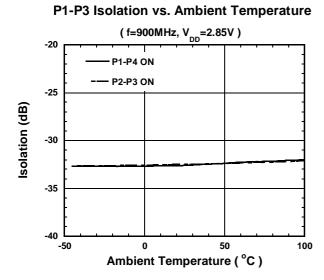


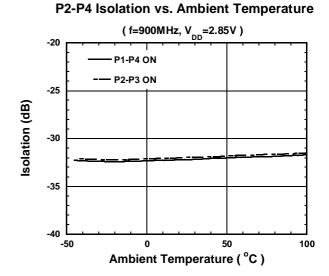
P3-P4 Isolation vs. Ambient Temperature

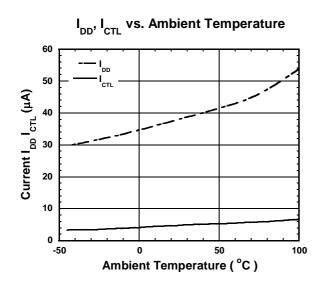


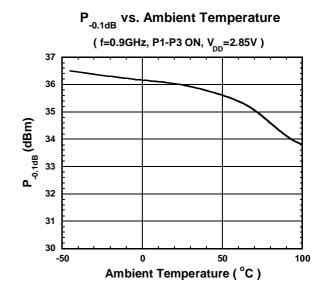
P3-P4 Isolation vs. Ambient Temperature

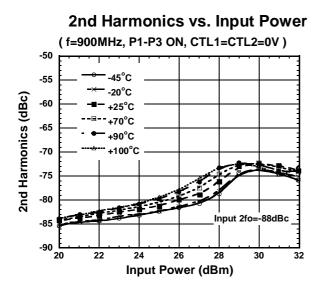


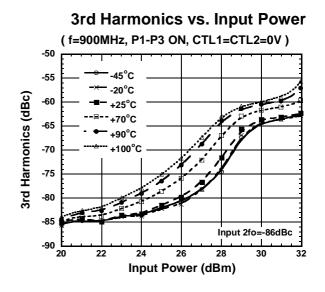


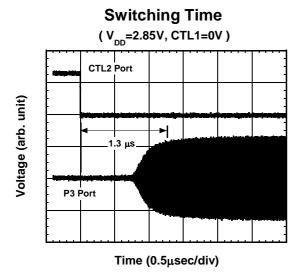


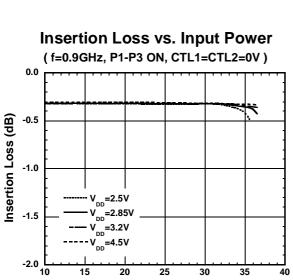




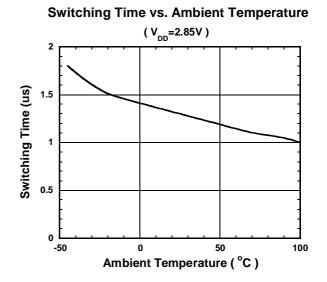


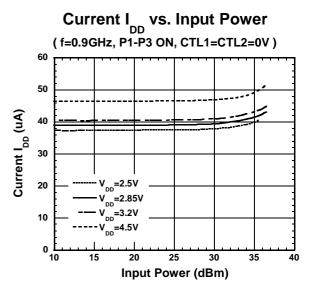




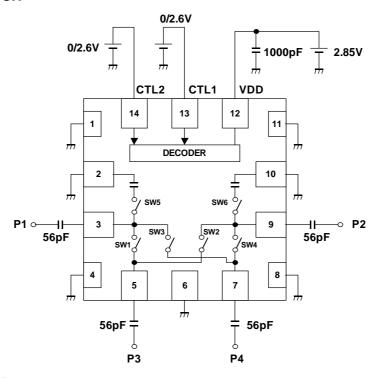


Input Power (dBm)



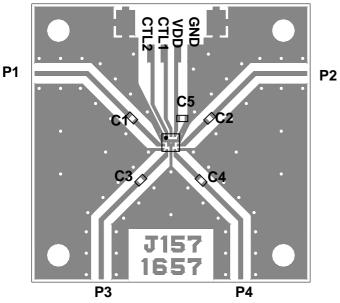


#### **■ APPLICATION CIRCUIT**



#### **■ TEST PCB LAYOUT**

(TOP VIEW)



PCB: FR-4, t=0.2mm

Capacitor size: 1005

Strip Line Width: 0.4mm

PCB size: 26 x 26mm

Losses of PCB, capacitors and connectors

Frequency (GHz)	Loss (dB)
0.9	0.30
1.9	0.49

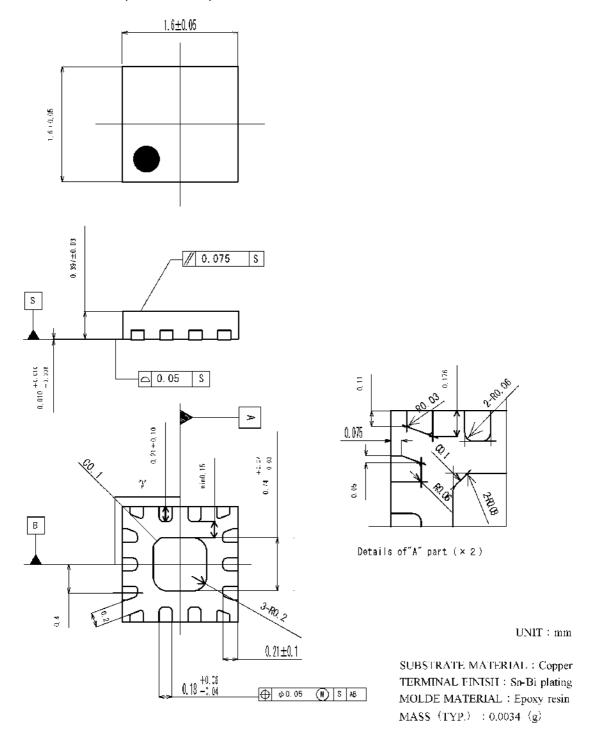
## **PARTS LIST**

PART ID	Value	COMMENT		
C1~C4	56pF	MURATA		
C5	1000pF	(GRM15)		

## **PRECAUTIONS**

- [1]The DC blocking capacitors have to be placed at RF terminal of P1, P2, P3, P4 and PC. Please choose appropriate capacitance values to the application frequency.
- [2]To reduce strip line influence on RF characteristics, please locate bypass capacitors(C5) as close as possible to each terminals.
- [3]For good isolation, the GND terminal must be connected to the ground plane of substrate, and through-holes for GND should be placed near by the pin connection.

## **■ PACKAGE OUTLINE** (EQFN14-D7)



## Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

#### [CAUTION]

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  - Various Safety Devices
  - · Traffic control system
  - Combustion equipment

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- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
  - 8-1. Quality Warranty Period
    - In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
  - 8-2. Quality Warranty Remedies
    - When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
    - Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
  - 8-3. Remedies after Quality Warranty Period
    - With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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